Operando Observation of Chemical Transformations of Iridium Oxide During Photoelectrochemical Water Oxidation

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ABSTRACT: Iridium oxide is one of the few catalysts capable of catalyzing the oxygen evolution reaction (OER) in both acidic and basic conditions. Understanding the mechanism of IrO_x under realistic photoelectrochemical conditions is important for the development of integrated water splitting systems. Herein, we have developed a highly efficient OER photoanode in pH 1 aqueous solutions based on a sputtered IrO_x film and a p+n-Si light absorber, interfaced with sputtered Au layer. Operando high energy resolution fluorescence detection X-ray absorption spectroscopy (HERFD XAS) was employed to monitor the oxidation state changes of IrO_x during both electrochemical and photoelectrochemical (PEC) water oxidation reactions in pH 1 aqueous solutions. We observed a gradual increase of the average oxidation state of Ir with increasing anodic potential in the pre-catalytic region, followed by a reduction of Ir under O_2 evolution conditions. Consistent results were obtained on dark anodes and illuminated photoanodes. However, when the thickness of IrO_2 was increased to 2 and 3 nm, the spectral changes became much less pronounced and the reduction of Ir oxidation state after the OER onset was not observed. This is due to the lower surface to bulk ratio, where lattice oxygen sites in the bulk are not accessible for the formation of hydroxide. More generally, the *operando* method developed here can be extended to other materials, thereby providing a powerful tool for mechanism discovery and an enabling capability for catalyst design.

Artificial photosynthesis, also referred to as solar fuels generation, provides an attractive approach to the chemical storage of solar energy as fuels, including as hydrogen generated from water.¹ A general approach for artificial photosynthesis is to use catalysts interfaced with light-harvesting semiconductors as photoelectrodes in photoelectrochemical (PEC) cells.² Silicon is a promising candidate as the photoelectrode due to its earth-abundance and efficient light-harvesting properties. However, the intrinsic instability of silicon in aqueous solution largely hinders its application in artificial photosynthesis. There has been significant progress in improving the stability of chemically sensitive

photoanodes, especially under extreme pH conditions. A variety of approaches, including introduction of passive or active catalytic corrosion protection layers, have been demonstrated.³⁻¹¹ However, for the oxygen evolution reaction, the majority of these have focused on alkaline conditions due to the narrower range of catalysts for acidic conditions.

Iridium oxide (IrO_x) is one of the rarely known materials that show both high OER catalytic activity and sufficient stability in acidic conditions.¹²⁻¹⁴ The chemical transformation of IrO_x has been studied both *ex situ* and *in situ* under electrochemical environments, mostly on model catalysts. For example, IrO_x electrocatalysts for the

OER have been investigated with synchrotron based X-ray absorption spectroscopy (XAS),15-16 X-ray photoelectron spectroscopy (XPS),17 and other techniques.16, 18-21 XAS at the Ir L_{III}-edge is a hard X-ray technique particularly suited for monitoring electronic structure changes under operando conditions, which provides information through X-ray absorption near edge structure (XANES) and extended X-ray absorption fine structure (EXAFS). The former, probed at the Ir L_{III}-edge, provides direct information on the unoccupied Ir 5d partial density of states. In particular, the Ir 2p-5d dipole excitation gives rise to a "white-line" absorption peak in the Ir L_{III}-edge spectrum, which can provide local information regarding the chemical state. For example, 40 nm thick anodic iridium oxide films were studied by XANES in 1 M H₂SO₄ by Huppauff and Lengeler.¹⁵ It was found that the Ir valence varied between 3 and 4.8 over the voltammetric region of approximately -0.24 V to +1.2 V vs. Ag/AgCl.15 In other work, electrodeposited iridium oxide films were examined in pH 7.3 and pH 10.7 buffer by Hillman et al. They proposed a two-site model and the average Ir valence change from 3.5 to 4.5 across the entire process.²² A similar behavior was recently observed using electrodeposited iridium oxide films investigated in 0.5 M H₂SO₄ by Minguzzi et al. and they proposed the co-existence of Ir(III) and Ir(V) under OER conditions.²³ However, sputtered iridium oxide films that were 21 nm and 59 nm thick, investigated in 1 M H₂SO₄ by Pauporte et al. showed different characteristics. They observed that the Ir valence only increased from 3 to 3.85 when the potential was increased from -0.24 V to +1 V vs. SCE (saturated calomel electrode).24 This discrepancy hints that strongly hydrated films, such as those formed via electrodeposition, exhibit different behavior under catalytic fundamentally conditions than relatively compact films formed via sputtering.

The apparent inconsistencies regarding Ir valence changes could have a number of possible origins. First, the short lifetime of the Ir 2p core-hole sets a rather broad energy resolution for conventional XAS (>5 eV), which limits the experimental sensitivity to reliably identify small spectral changes or energy shifts.²⁵ Second, as mentioned above, the iridium oxide films made from different methods may have intrinsically different characteristics, which are additionally complicated when analyzed under applied bias and in different pH solutions. Third, and finally, appropriate experimental setups for *operando* measurements are challenging to realize but are required to obtain reliable results.

Most of these *operando* studies of $\rm IrO_x$ catalysis were directed at elucidating mechanisms and, therefore, were applied to model systems. However, it is also important to recognize that solar fuels devices often require these catalysts to be integrated onto semiconductor light absorbers and for the interfaces between the catalyst and semiconductor to be engineered to ensure stability of the complete assembly, efficient charge transport through the interface, and minimal parasitic light absorption in the catalyst. 26 All of this must be accomplished without

sacrificing catalytic activity. Since these engineered systems comprise significantly more complexity than the model system counterparts, it is essential to characterize realistic photoelectrodes.27-30 Furthermore, an efficient catalyst needs to be thin enough to avoid parasitic light absorption, and compact enough to protect the chemically semiconductors against sensitive chemical photochemical corrosion for PEC applications.⁵ Therefore, the thick and porous electrocatalytically active films that have been investigated to date are not compatible with many PEC systems, and the catalytic behavior may not be transferable to the surface behavior of realistic catalysts for photoanodes. Using a realistically working photoanode to directly investigate the OER mechanism under PEC conditions is challenging, 24,31 but critical for achieving relevant insights and advancing the development of efficient integrated PEC systems.

Compared to conventional XAS, high energy resolution fluorescence detection XAS (HERFD XAS), in which an energetically narrow portion (~1 eV) of a selected fluorescence line is monitored, results in significantly improved resolution of X-ray absorption spectra.^{25, 32} Furthermore, the high energy resolution of the detected xrays limits any influence of the strong elastic and Compton scattering background signal from the electrolyte, which is typically one order of magnitude higher than the fluorescence signal of the metallic species of interest.33 This advantage allows the study of ultrathin catalyst (down to sub mono-layer structures) despite the presence of electrolyte within an electrochemical cell.33 We have shown that operando electrochemical HERFD XAS provides a unique sensitivity to the structure and chemical bonding at the Pt-electrolyte interface,34-37 and allows monitoring of electronic structure changes in earthabundant 3d transition metal catalysts for the OER.38-39

A sputter-deposited Ir/IrO_x film stack on p+n-Si, where the interfacial Ir served as a protection layer for chemically sensitive Si and IrO_x acted as the catalyst, was previously reported and exhibited efficient water oxidation in acidic media (1 M H₂SO₄).9 This work inspired us to directly investigate the oxygen evolution reaction (OER) mechanism on sputtered IrO2 film on p+n-Si using the operando XAS technique. Here, considering the local interaction between Au and metal oxides, 40-41 we explore the Au as an interfacial layer between the IrO_x catalyst and the Si photoanode, i.e., photoelectrodes comprise IrO_x/Au/p+n-Si and dark electrodes comprise IrO_x/Au/p+-Si. The thickness of the ultrathin (1-3 nm) but robust IrO_x was optimized and studied by operando Ir-L_{III} HERFD XAS in 1 M H₂SO₄ solution, under simulated air mass (AM) 1.5 illumination and dark conditions, respectively, thereby allowing us to access the chemical state information exclusively on the ultrathin IrO, layer during the OER reactions.

Results and discussion

1. Physical and electrochemical properties of $IrO_2/Au/Si$ versus $IrO_2/Ir/Si$.

Figure 1 (a) shows a comparison of cyclic voltammograms (CVs) from IrO₂/Au/p+n-Si photoanodes versus IrO₂/Ir/p+n-Si photoanodes under simulated AM 1.5 irradiation at 100 mW/cm². Also shown in Figure 1(a) are the same catalyst layers applied to degenerately doped p+-Si (0.001-0.005 Ω cm⁻¹, denoted as p⁺-Si) in the dark. All CVs were acquired in 1.0 M H₂SO₄. In all cases, the nominal thickness of IrO₂ was 4 nm, as determined by a quartz crystal monitor in the sputtering system. This layer thickness was selected to provide adequate catalytic activity while keeping parasitic light absorption low, as well as to enable comparisons with previously reported data.9 Comparing the photoanode to the dark electrode, the onset potential, defined at the potential required to achieve a current of 1 mA/cm², was found to shift by ~490 mV in the cathodic direction, from 1.63 V vs. RHE for IrO_x/Ir/p⁺-Si in darkness to 1.12 V vs. RHE for IrO_x/Ir/p⁺n-Si under illumination. The onset potential and photovoltage, though not fully optimized, are comparable to the previously reported results. When an interfacial Au layer was used instead of Ir, the onset potentials for both the dark electrode and photoanode under illumination exhibited favorable cathodic shifts of approximately 100 mV, with values of 1.54 V vs. RHE for $IrO_x/Au/p^+$ -Si and 1.04 V vs. RHE for IrO_x/Au/p+n-Si, which yields a photovoltage of 500 mV. Comparing the Au interfacial layer to the Ir interfacial layer, the photocurrent density at 1.23 V vs RHE increased from 5 to 13 mA cm⁻² and the saturation current density increased from 13 to 18 mA cm⁻² for the IrO_x/Ir/p⁺n-Si and IrO_x/Au/p+n-Si, respectively. A similar increase of current density at a given applied electrochemical potential was observed for the catalysts deposited on p+-Si. These results indicate that the Au interfacial layer yields better performance than the Ir interfacial layer for both EC and PEC on Si. To reveal the reason of this improvement, the physical properties of these two types of electrodes were characterized, as discussed below.

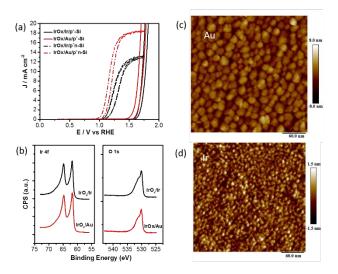


Figure 1. (a) Cyclic voltammogramms for IrO₂/Ir/Si (black) and IrO₂/Au/Si (red) dark electrodes (dashedsolid) and photoelectrodes (dashedsolid) operated in 1 M H₂SO₄, (b) X-ray photoelectron spectra of the Ir 4f and O 1s core levels from

IrO₂/Ir/Si (black) and IrO₂/Au/Si (red), and (c,d) atomic force micrographs for IrO₂/Au/Si (c) and IrO₂/Ir/Si (d).

Chemical analysis via X-ray photoelectron spectroscopy (XPS) was performed to determine whether differences in composition between IrO_x deposited on Ir and on Au are present. Ir 4f and O is core level regions are shown in Figure 1(b), reveal that the compositions of IrO_x in the two types of samples are very similar. In particular, despite different interfacial layers, both comprise IrO_2 , with binding energies of Ir $4f_{7/2}$ and Ir $4f_{5/2}$ at 61.9 eV and 63.9 eV, respectively.⁴² The broadness of the Ir 4f peak indicates the deviation of IrO_2 from standard rutile structure in both cases, and the asymmetry in both Ir 4f core-level peaks arise from conduction electrons screening both Ir 4f and O is core-holes.⁴³⁻⁴⁴

Given the absence of chemical differences, the morphologies of the two types of films were examined. The surface topographies of IrO₂/Au/p+n-Si and IrO₂/Ir/p+n-Si, determined via atomic force microscopy (AFM), are shown in Figure 1(c) and (d), respectively. These measurements reveal a much rougher surface of IrO₂/Au/p+n-Si than IrO₂/Ir/p+n-Si, with rms surface roughness values of 1.6 nm and 0.4 nm, respectively. AFM characterization of the samples prior to IrO_x deposition reveals that this is a consequence of a rougher Au/p+n-Si interface layer, which is characterized by a nanoparticulate morphology, likely as a consequence of dewetting due to direct deposition on the Si substrate (Figure S1). In contrast, the Ir layer on Si is extremely smooth (Figure S1). Consequently, it is likely that the increased surface area and thus increased concentration of active sites per geometric area could lead to a higher activity.

2. (Photo)electrochemical study on $IrO_2/Au/p^+(n)$ -Si with different IrO_2 thicknesses

We further investigated the effect of thicknesses of IrO_2 layer on the CV performance, aiming to obtain an optimum thickness for subsequent XAS studies. Three different thicknesses of IrO_x on Au/p^+n -Si and Au/p^+ -Si were prepared by controlling the sputtering time to achieve films of 1 nm, 2 nm, and 3 nm thickness.

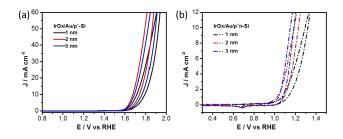


Figure 2. Cyclic voltammogram of IrOx with different thicknesses (1 nm, 2 nm, and 3 nm) on Au/p⁺-Si (a) in the dark and Au/p⁺n-Si (b) under AM1.5 solar simulator irradiation in 1M $\rm H_2SO_4$ aqueous solution measured at a scan rate of 100 mV s⁻¹.

Figure 2 shows cyclic voltammograms (CVs) of IrO₂ with thicknesses of 1, 2, and 3 nm on p+Si in the dark and on

p+n-Si under 100 mW cm⁻² irradiation in 1 M H₂SO₄. The dark anodes and illuminated photoanodes show an electrochemical oxidation pre-feature at ~1.3 V vs. RHE and ~o.8 V vs. RHE, respectively, followed by the steep onset of OER current. The precatalytic region wasis enlarged and shown in Figure S8. The electrochemical features in the pre-catalytic region are related to oxidation/reduction and/or charging of IrO_x, though the assignment of chemical state transformation during those periods is still unclear and controversial.^{23, 45-46} It was proposed that these features are related to a sort of "pre-rutile" structure, which is a non-interacting octahedral structure.23 The redox current and OER current on the thinnest sample, i.e., 1 nm, are slightly lower compared to those on the 2 nm thick sample, but further increase of the thickness of IrO2 to 3 nm had little additional impact on the CV characteristics. This trend is significantly different from the previous report on the IrO_x/Ir/p+n-Si, where 2 nm IrO_x showed much lower initial activity than the 4 and 6 nm ones.9 This is likely a consequence of the high surface area of the catalyst on Au, which provides a larger concentration of active sites, even for thinner layers. Next, we will compare the operando XAS experiment on these samples under illumination and in the dark.

3. Operando XAS investigation of the ultrathin $IrO_2(1 \text{ nm})/Au/p^+n$ -Si under light illumination and $IrO_2(1 \text{ nm})/Au/p^+$ -Si in the dark

Investigation of the ultrathin IrO₂ catalyst layers was performed under real PEC/EC OER conditions using the experimental setup shown schematically in Figure 3(a). The PEC cell was based on a three-electrode configuration in which the sample under investigation was used as the working electrode (WE), a Pt wire was used as the counter electrode (CE), and a Ag/AgCl electrode was used as the reference electrode. The WE was placed ~2 mm above the opening of the H-cell to form a hanging electrolyte meniscus. A 100 W heatless Xenon light source (LAX-C100, Asahi Spectra, USA) was used to illuminate the samples for PEC measurements. This configuration enabled study of the operando catalyst transformation as a function of the applied electrochemical potential.

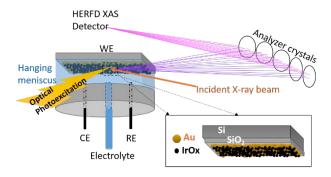


Figure 3. Schematic diagram of the *operando* (photo)electrochemical HERFD XAS experimental setup and the model of a photoelectrode.

A typical XAS spectrum is shown in Figure S2, where the most striking characteristic is a sharp and intense peak,

which is referred to as the white-line and arises from $Ir2p \rightarrow 5d$ electronic transitions. Therefore, the white-line provides direct information about the Ir 5d unoccupied density of states. The energy position of the white-line indicates the oxidation state of Ir, which shifts by approximately +1.5 eV for each additional 5d hole, for example, when the oxidation state changes from Ir(III) (5d⁶) to Ir(IV) (5d⁵).⁴⁷ Thus, in the present work, we primarily focus on analyzing the change of the white-line as a function of applied electrochemical potential and illumination condition in order to characterize transformations of the IrO_x catalyst that occur as it moves from the resting to active state.

X-ray absorption spectra obtained from the as-deposited catalyst in a dry environment are compared with the immersed catalyst at the open circuit potential (OCP) and the reference samples of K₃IrCl₆ and IrO₂ (Figure S₃). Upon exposure of the catalyst layer to the aqueous electrolyte, we observed a shift of the white line position to lower energies. To estimate the average oxidation states of IrO_x, the whiteline positions of the spectra are extracted by fitting the center of the spectra using a Gaussian peak function. The references samples of K₃IrCl₆ to IrO₂ give the peak positions of 11217.14 ± 0.01 eV and 11218.63 ± 0.02 eV, which correspond to Ir(III) and Ir(IV), respectively. This reference measurement is in agreement with the previous studies and confirms the expectation of a 1.5 eV shift per oxidation state for Ir(III) and Ir(IV).15, 23, 46, 48-51 A linear relationship between the white line positions and valence state change are used to obtain the average oxidation states of IrO_x. 15, 23, 46, 48-51 Using the same linear relationship, we estimate the average oxidation states of Ir in IrO_x to be 3.98 and 3.43 for the dry and wet conditions, respectively. This suggests that partial reduction of IrOx from Ir(IV) to Ir(III) occurs underin the OCP conditions, leading to the formation of an oxyhydroxide in the fashion of IrO(OH)This suggests that exposure of IrO, to the aqueous electrolyte leads to partial reduction of IrO_x from Ir(IV) to Ir(III). The effect of the aqueous electrolyte could be understood by the formation of an oxyhydroxide in the fashion of IrO(OH).52-53

After evaluating the transformation of the catalyst layer upon solid/liquid interface formation at the OCP, we measured XAS of all the samples over a range of potentials, including a potential well below the water oxidation potential, at potentials below and above the redox potential commonly assigned to the Ir(III)/Ir(IV) transition, and to a potential at which significant oxygen evolution occurs, which is referred to as the *operando* condition.

Considering that Ir $L_{\rm III}$ XAS is a "bulk" sensitive hard X-ray probe that provides average information of the whole film, three thicknesses of ${\rm IrO}_x$ film (3 nm, 2 nm, and 1 nm) were examined in order to extract information related to surface transformations during catalysis. These three thickness offer different surface to bulk ratios; the 1 nm ${\rm IrO}_x$ film provides a higher surface to bulk ratio than the 2 nm and 3 nm ${\rm IrO}_x$ films. These ${\rm IrO}_x$ films on ${\rm Au/p^+-Si}$ in the dark and ${\rm Au/p^+-Si}$ under irradiation were examined

by *operando* HERFD XAS at a series of potentials. The normalized XAS data are shown in Figure S4. All spectra in Figure S4 show the presence of strong white-line features indicating that there is a large local density of unoccupied 5d states at all potentials.²³ For both the dark electrode Au/p⁺-Si and photoanode Au/p⁺n-Si, the energy positions of the white-line gradually shift towards higher energies as the potential increased up to OER conditions. Such a shift

indicates an increase in the Ir oxidation state, which is in qualitative agreement with previous reports using conventional XAS.²⁴ The average oxidation states of Ir at different potentials were estimated based on the linear relationship between white line positions and Ir oxidation states (Figure S5 in SI).

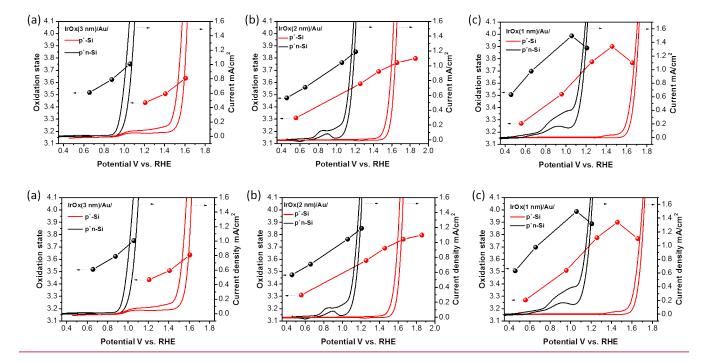


Figure 4. Cyclic voltammetry (right axis) recorded at 100 mV s⁻¹ in aqueous 1M H_2SO_4 and corresponding Ir oxidation state (left axes) on $IrO_x/Au/p^+$ -Si (red line) and $IrO_x/Au/p^+$ n-Si (black line) as a function of applied potential. The thickness of IrO_x is 3 nm (a), 2 nm (b), and 1 nm (c).

The average oxidation states of Ir at different potentials, together with corresponding CVs on IrO_x/Au/p+-Si (red line) and IrO_x/Au/p+n-Si (black line), are shown in Figure 4. For the 3 nm thick IrO_x in Figure 4 (a), the average oxidation state of Ir on the photoanode p+n-Si (black dot) increased in parallel with that of dark anode p*-Si (red dot) as a function of applied potential. The difference of the potentials between the photoanode and dark anode are due to the photovoltage generated in the former under illumination. This trend of the average oxidation state with increasing voltage is similar to thinner IrO_x films of 2 nm Figure 4 (b). Though they exhibit a similar trend, the shifts for 2 nm thick films are more pronounced than for 3 nm thick films (Figure S4 (a-d)). These pronounced shifts suggest larger changes in average oxidation states for 2 nm compared to 3 nm IrO_x films (Figure 4(a & b)). For example, the average oxidation states reaches 3.76 and 3.86 at pre-OER and OER potentials, respectively, respectively on for the 2 nm electrode, while the corresponding average oxidation states for theof 3 nm-dark electrode are 3.62 and 3.74 at pre-OER and OER potentials, respectively. We further reduced the thickness of IrOx to 1 nm, shown in Figure 4 (c). As the potential is increased from 0.56 to 1.46 V vs. RHE for the dark electrode, the average oxidation state gradually increases, and reaches the maximum at the potential after the pre-catalytic Ir oxidation peak and right before OER occurs (red dots in Figure 4 (c)). The trend of the average oxidation state with increasing voltage is similar to thicker IrO_x films of 2 nm and 3 nm. However, it is worth noting the shifts for 1 nm thick films are more pronounced than for 2 nm and 3 nm thick films. Importantly, the average oxidation state decreased upon further increase of the potential from 1.46 to 1.66 V vs. RHE, where OER vigorously occurs. This phenomenon is observed for both non-photoactive anodes (p+-Si) and photoactive anodes (p+n-Si). The reduction of Ir oxidation state in the OER region proves the free energy DFT calculations by Nørskovet.al.54 They proposed that the most stable intermediate just below the onset of OER is fully covered with atomic $O(IrO_x-O)$, giving Ir the highest average oxidation state. The ilncrease of the potential above the onset of OER, results in the release of O2 and produces empty sites, which . The empty sites lead to lowers the average oxidation states of Ir, as shown we see in Figure 4 (c). The increase of the potential above the onset of OER, results in the release of O2 and produces empty sites not coordinated to atomic O. This lower coverage of atomic O leads to lower average oxidation states of Ir, as

we see in Figure 4 (c). The shifting of oxidation states towards lower states has also been observed by XAS on electrodeposited IrO_x films, which are porous and thicker under EC,²³ but was not clearly observed on other IrO_x films.^{15, 46, 48-51}

In addition to the change of the white line position at different electrochemical potentials, it is also found that the width of the white-line increases as the potential is increased in Figure S₄ (e & f). This effect can be understood in terms of the co-existence of two or more species with different oxidation states and induced broadening arising from crystal field split transitions.^{23, 47} The crystal field split transitions may be observed in the second derivative of the spectra, which is characterized by two negative peaks when the bandwidth of the Ir 5d states is smaller than the crystal field splitting.55 These two negative peaks correspond to the transition from the Ir 2p levels to the split $(t_{2g} + e_g)$ 5d states.56 The second derivatives of the spectra are shown in Figure S6. The single-peak with the presence of a shoulder in the second derivative spectra indicates that the broadening we observed in Figure S4 (e & f) cannot be attributed to crystal field splitting.23, 47 In another words, the increase of the width of the spectra with potential is due to the two or more species with different oxidation states, i.e., Ir(III), Ir(IV) and Ir(V). The Ir(V) feature was

suggested to only exist at the topmost surface of IrO, nanocrystals by our group using ambient pressure XPS (APXPS), which is surface-sensitive technique.¹⁷ Moreover, interpretation of XAS at the Ir L_{III} edge has led to the suggestion that the transformation of Ir(V) exists on anodic iridium oxide films and electrodeposited iridium oxide films.13,57 However, Ir(V) was not observed on sputtered films.^{15, 46, 48-51} This could be due to the differences in the composition, phase or structure of the films. Materials could transform differently as a function of deposition method.⁵⁸ The anodic and electrodeposited films are usually heavily hydrated porous materials, where nearly all the Ir sites are accessible to electrolyte and likely to enable more facile transformation to higher oxidation states during the reaction. In contrast, sputtered films are dense and anhydrous, where only the Ir sites located at the surface are accessible to electrolyte.-, as compared to the dense and anhydrous films made by sputtering. Moreover, Ir(III) associated with O(1-) species instead of Ir(V) was proposed during OER, using XPS, XAS and theoretical calculations. ^{36, 59} In the present work, the IrO₂ film with the highest degree of transformation is 1 nm thick, but

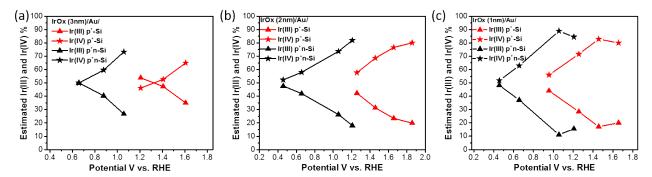


Figure 5. Estimated amount of Ir(III) (triangular) and Ir(IV) (star) as a function of applied potentials (a) IrO_x (3nm), (b) IrO_x (2nm) and (c) IrO_x (1nm) on Au/p^+ -Si (red line) and Au/p^+ n-Si (black line).

it is clear that Ir(V) is not the dominant component in the bulk materials during the catalytic process, as concluded from the average oxidation states discussed above.

Assuming the exclusive co-existence of Ir(III) and Ir(IV), the XAS spectra of Ir were fitted with a combination of an arctan step function and two Gaussian peaks with the fixed maxima positions at 11217.14 \pm 0.01 eV and 11218.63 \pm 0.02 eV, based on white lines of our Ir(III) and Ir(IV) references extracted from K₃IrCl₆ and IrO₂, respectively. The proportion of the Ir(III) and Ir(IV) obtained from relative areas of the fitted Gaussian peaks are plotted as a function of applied potential (Figure 5).

The quantitative analysis based on fitting of XAS also shows that when the potential is increased from the precatalytic region to OER potentials, the concentration of Ir(IV) increases as the concentration of Ir(III) decreases in an almost linear way for both dark anodes (p⁺-Si) and

illuminated photoanodes (p*n-Si) for all the thicknesses, as shown in Figure 5 (a), (b), and (c). For instance, as seen in the Figure 5 (b), when the potential is increased from 0.58 to 1.46 V vs. RHE, the concentration of Ir(IV) increases while the concentration of Ir(III) decreases. Moreover, the dependences on potentials are nearly linear for both dark anodes (p*-Si) and illuminated photoanodes (p*n-Si) for all cases. With further increase of the potential to the OER region, the dependence on potential continues nearly linearly for both 3 nm and 2 nm IrO_x. However, for 1 nm IrO_x on p*-Si, further increase of the potential from 1.46 to 1.66 V vs. RHE, where OER occurs, leads to a slight decrease of Ir(IV) and slight increase of Ir(III). It is worth noting that the concentration of Ir(IV) remains above 80% for both photo and dark anodes in the OER region.

The difference of thicker films and ultra-thin films are interpreted in detail at below and above the OER onset potentials as follows.

First, the transformation below the onset of OER is much more significant on the 1 nm film. Comparing the photoanodes for example, at potentials just below onset of OER. i.e., 1.06 V vs RHE, the Ir(IV) on the 1 nm sample reaches a maximum of $\sim 90\%$, while the value on the 2 nm and 3 nm samples are only about ~75%. This confirms that the catalytic transformation occurs on the surface rather than the bulk of the IrOx. For thicker films with lower electrolyte-accessible surface to volume ratio, the change is not as pronounced since a smaller fraction of the Ir atoms participate in catalytic reactions. This surfacelimited transformation behavior confirms that our film is distinct from a "homogeneous" layer, which should yield a constant ratio of transformed Ir with changing film thickness, as seen in the electrodeposited layers.23 However, our film is also not an absolutely dense layer, which should yield half the fractional Ir transformation with a doubling of the thicknesses, i.e., 45% vs. 90%. The origin of the disproportionate Ir redox activity can be understood by inspection of cross sectional TEM images (Figure S₇). A film of ~4 nm IrO₂ layer on Au/Si shows that the IrO₂ layer consists of stacked 1-2 nm IrO₂ nanocrystals. On the 1 nm layer sample, the surface to bulk ratio is very high, resulting in transformation of 90% of the Ir atoms to Ir(IV). With increasing layer thickness to 2 nm, the nanocrystals are enlarged or stacked together, making the total surface area of nanocrystals larger than that of the 1 nm sample, but by less than a factor of two, so the ratio of surface of catalyst accessible to electrolyte to bulk materials is smaller.

Second, when the potential is swept above the onset potential of OER, the catalytic water oxidation by Ir(IV) is accompanied by the release of O₂ and leads to a reduction of Ir(IV) to Ir(III). At the same time, the oxidation of Ir(III) to Ir(IV) continues to occur. On the 1 nm sample with almost all of the Ir transformation to Ir(IV) (90%) below the onset potential, further oxidation is limited, so an average reduction of Ir(IV) to Ir(III) is observed. In contrast, the reduction of Ir at anodic potentials beyond the onset of OER is not observed for the case of the thicker films due to continuous oxidation of Ir(III) to Ir(IV) within the material. The oxidation of Ir(III) to Ir(IV) creates more active sites for water oxidation and the greater degree of Ir transformation on the 2 nm sample than on the 1 nm sample leads to a higher OER current (Figure 2). Further increase of film thickness from 2 nm to 3 nm does not improve the OER current further, likely since material deeper within the sample does not contribute to the reaction. Moreover, for a photoanode, where parasitic light absorption must be minimized, keeping the film as thin as possible is essential. Therefore, with a catalyst film with stacked nanocrystals, the optimal thickness for OER process in the sputtered films is balanced among the oxidation of water and catalyst itself, as well as kinetic release of O2. In our case, the optimal balance occurs at a thickness of approximately 2 nm.

Conclusion

We developed an efficient IrO₂/Au/p+n-Si photoanode operating in acidic solutions. The use of Au as the

interfacial layer results in lower onset potential, higher photocurrent, and higher photovoltage when compared to the reported Ir interfacial layer. The improvement could be related to the rougher surface of Au, as revealed by AFM and cross sectional TEM. The resulting IrO2 thin film exhibited nanocrystals with the structurally labile surface and good coverage on Au with more exposed active sites, thereby leading to a superior photo and dark OER current. IrO, ultrathin films with controlled thicknesses were prepared by a sputtering process and the catalytic transformation properties were studied by operando HERFD XAS during OER under both EC and PEC conditions. On the ultrathin (1 nm) IrO2 film, the average Ir oxidation state increases with increasing applied potential and reaches a 90% of transformation just below the OER onset potential. Above the onset potential, the ultrathin films show a decrease in oxidation state. This phenomenon is consistent with the free energy DFT calculations based on (110) surfaces of rutile-type IrO, proposed by Nørskov et.al.54 Moreover, we shows the first experimental evidence of reduced Ir at OER under realistic PEC conditions. When we increase the thicknesses of IrO₂, the spectral changes become much less pronounced. This is due to the lower electrolyte-accessible surface to bulk ratio, where inner regions of the film are not accessible for the formation of hydroxide. This result further proves that the reaction is limited to the near-surface region of the IrO_x film, which agrees with our earlier operando XPS study.17 At potentials beyond the OER onset potential, the average oxidation state kept increasing on thicker films. By correlating the Ir oxidation state change results and OER performance (J-V) data, we can conclude the balancing properties that yield optimum thickness for PEC and EC performance. The XAS operando study provides important insight into observing the catalytic process and the optimum catalyst design compatible for sensitive photoanodes

Supporting Information.

Experimental details, activity measurements, AFM, TEM, and *operando* HERFD-XAS measurements. This material is available free of charge via the Internet at http://pubs.acs.org.

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ABBREVIATIONS

OER, oxygen evolution reaction; HERFD XAS, high energy resolution fluorescence detection X-ray absorption spectroscopy; PEC, photoelectrochemical; CV, cyclic voltammograms;

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